



FEATURES

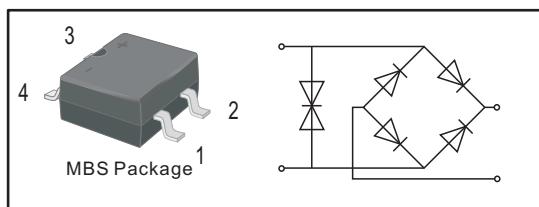
- Lead Free Finish/RoHS Compliant
- Green Molding Compound (No Halogen and Antimony)
- Large withstanding surge current capability : 200A/220A (@8/20μs)
- Lower clamping voltage and excellent performance on ringing waves testing.
- Glass Passivated Chip Junction
- High Surge Current Capability
- Designed for Surface Mount Application

PINNING

PIN	DESCRIPTION
1	Input Pin (~)
2	Input Pin (~)
3	Output Anode (+)
4	Output Cathode (-)

MECHANICAL DATA

- Case: MBS
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 100mg / 0.0035oz



Maximum Ratings and Thermal Characteristics(TA = 25°C unless otherwise specified)

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter of Bridge Rectifier	Symbols	TB120S	TB240S	TB250S	TB120SA	TB240SA	TB250SA	Units
Average Rectified Output Current at T _c = 125 °C	I _o			1.0				A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}			35				A
Maximum Forward Voltage at 1.0 A	V _F			1.1				V
Maximum DC Reverse Current @T _A =25 °C at Rated DC Blocking Voltage @T _A =125 °C (@VR=1000V)	I _R			5 40				μA
Typical Junction Capacitance (f=1MHz,4V DC)	C _j			13				pF
Typical Thermal Resistance (Note1)	R _{θJA} R _{θJC}			80 28				°C/W
Operating and Storage Temperature Range	T _j , T _{stg}			-55 ~ +150				°C

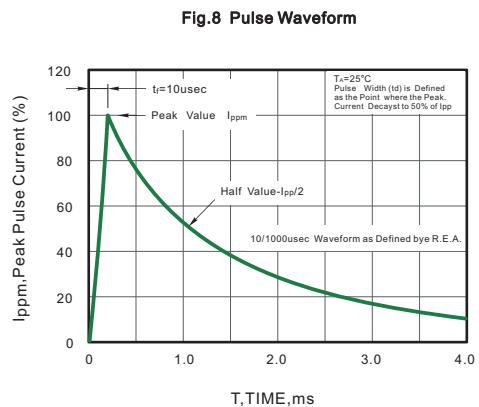
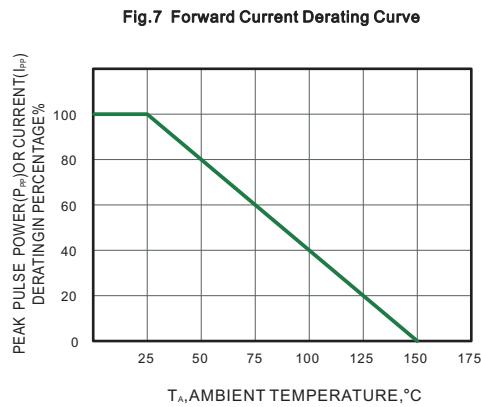
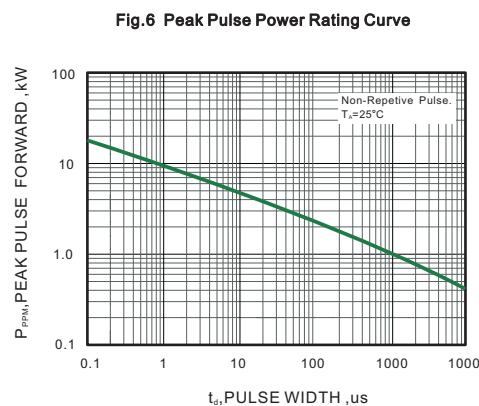
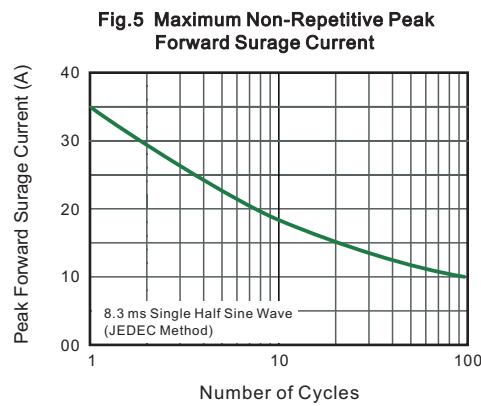
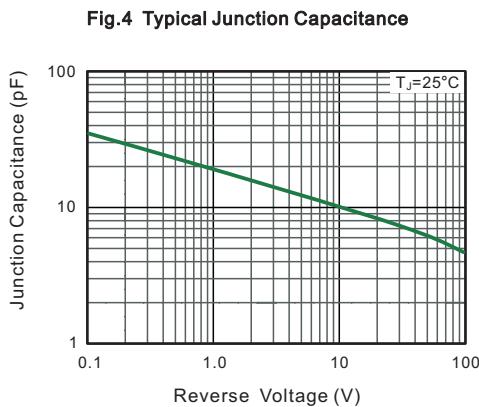
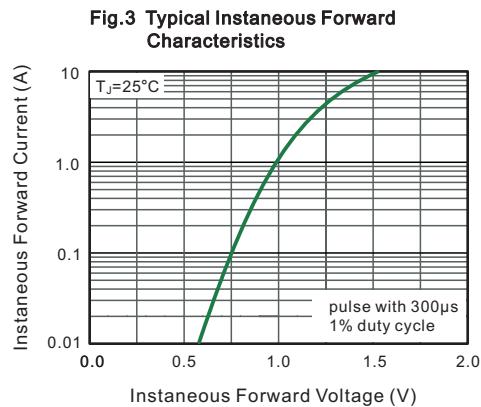
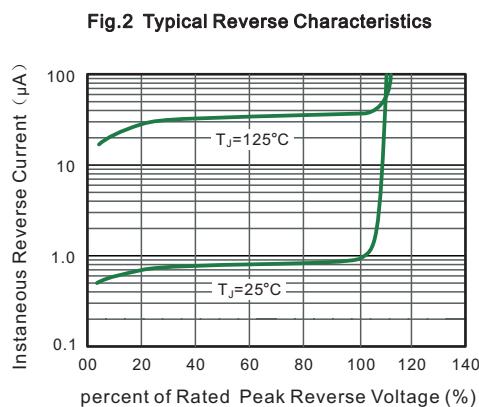
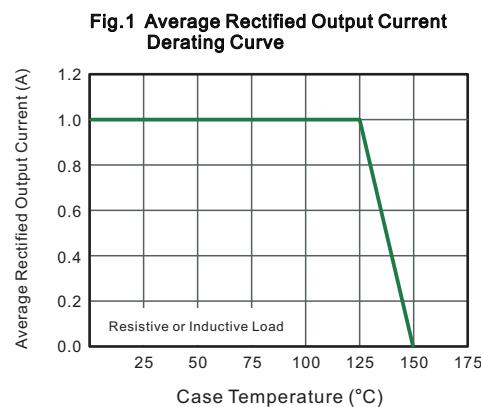
Note: 1. Mounted on glass epoxy PC board with 4×1.5"×1.5" (3.81×3.81 cm) copper pad.

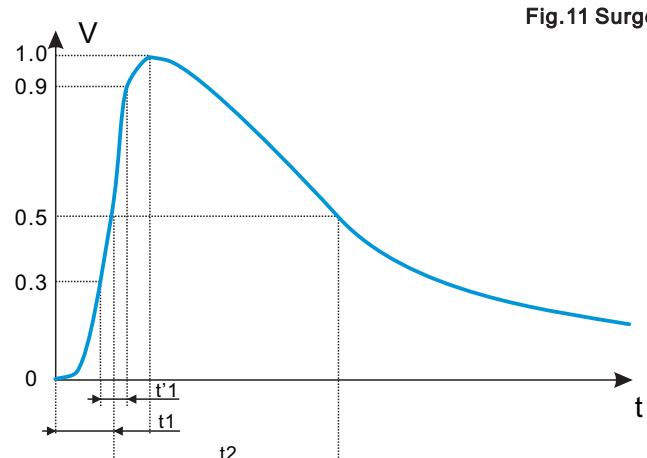
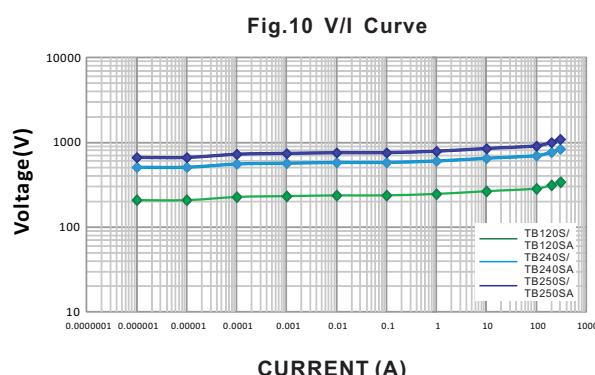
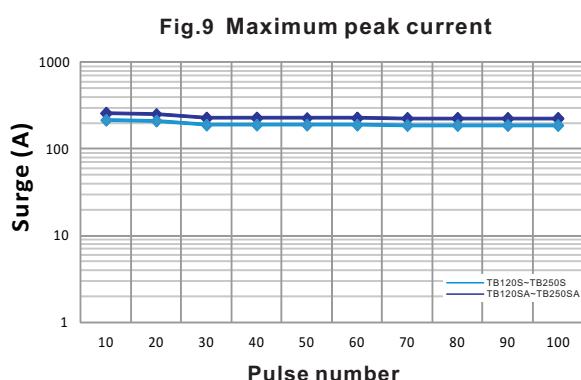
Parameter of TVS	Symbol	TB120S	TB240S	TB250S	TB120SA	TB240SA	TB250SA	Unit
Maximum allowable continuous AC voltage at 50-60Hz	V _{RMS}	155	310	380	155	310	380	V
Breakdown voltage @ 1mA	V _{BR}	237~263	492~543	551~609	237~263	492~543	551~609	V
Maximum allowable continuous DC voltage	V _{DC}	220	440	490	220	440	490	V
Maximum allowable clamping voltage @ 8/20us(Fig 10)	V _C	350	700	850	350	700	850	V
Maximum peak current (8/20μs@2Ω)(Fig 9)	I _{peak}		200			220		A
Peak Pulse Current on 10/1000 us waveform (Note 2, Fig 7)	I _{PPM}				See Table 1			A
Operating and Storage Temperature Range	T _j , T _{stg}			-55 ~ +150				°C

Table 1

Type	Typ. Clamp Voltage V _C @ I _{PP} (V)	Peak Pulse Current@10/1000us I _{PP} (A)
TB120S	290	2.2
TB240S	630	1.2
TB250S	680	0.9
TB120SA	290	2.6
TB240SA	630	1.6
TB250SA	680	1.3

NOTE2:Non-repetitive current pulse, per Fig.8 and derated above TA = 25°C per Fig. 7.

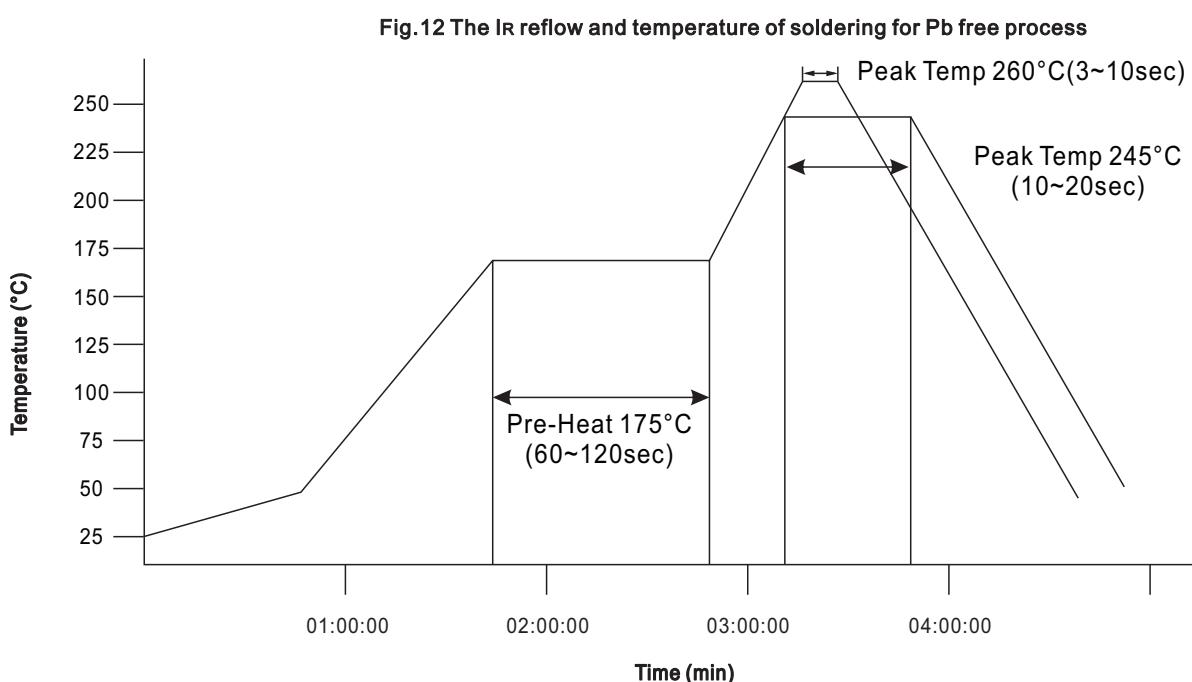




IEC61000-4-5 Standards

SEVERITY LEVEL	T1(=1.67t'1)	T2
1	10us	1000us
2	8us	20us

8/20us waveform current



IR reflow Pb free process suggestion profile:

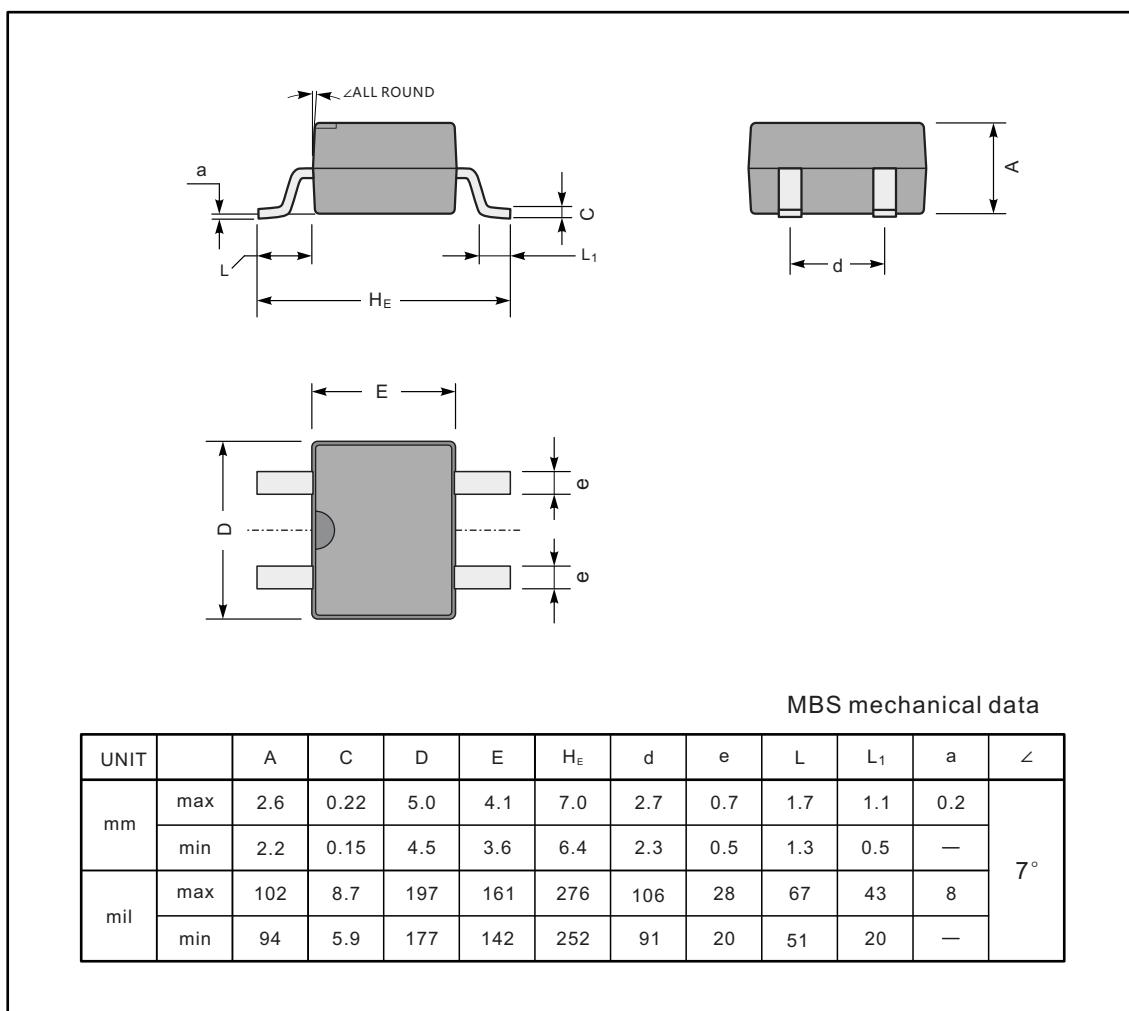
- (1) Ramp-up rate (217°C to peak) +3°C/second max.
- (2) Temp. maintain at 175±25 180seconds max.
- (3) Temp. maintain above 217°C 60~150 seconds
- (4) The peak temperature must be at least 260°C, the time above the 255°C must be within 20s



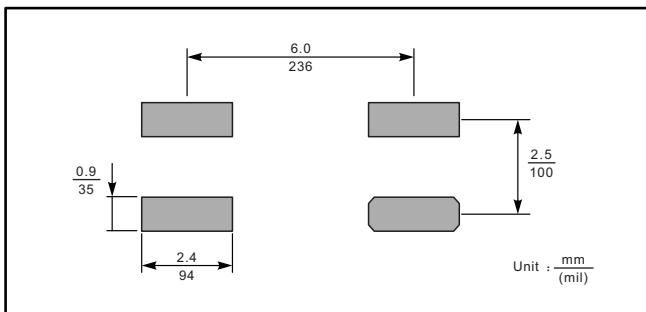
PACKAGE OUTLINE

Plastic surface mounted package; 4 leads

MBS



The recommended mounting pad size



Marking

Type number	Marking code
TB120S	TB120S
TB240S	TB240S
TB250S	TB250S
TB120SA	TB120SA
TB240SA	TB240SA
TB250SA	TB250SA

TBXXS/SA